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(57) Abstract:

PROBLEM TO BE SOLVED: To obtain a member, useful as the one used in a production process for semiconductors and excellent in dimensional retention accuracy for a stress and a temperature changes, suppression of damage to a silicon wafer and prevention of particles from sticking by forming a titanium oxide film of a specific composition on the surface of a silicon nitride or sialon having a specific average thermal expansion coefficient as a substrate and composing the member. SOLUTION: This ceramic composite film is composed by forming a TiO2-x [2>(x)>0] film or a film comprising a mixture composition of the TiO2-x and TiO2 having the thickness of preferably ?1% that of silicon nitride or sialon as a substrate which is a dense sintered compact, obtained by adding a sintering assistant, e.g. Y2O3, Al2O3 or MgO in the total amount of ?15% to the silicon nitride or sialon and sintering the resultant mixture by atmospheric sintering, gas pressure sintering or hot isostatic press (HIP) sintering and having ?95% relative density and ?1.5×10-6/°C average thermal expansion coefficient between 20 and 50°C on the surface of the substrate.

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